

Quad Programmable Bipolar JFET Operational Amplifiers

GENERAL DESCRIPTION

The XR-094 and XR-095 bipolar JFET input quad programmable operational amplifiers consist of four independent, high gain, internally compensated amplifiers. Two external resistors (R_{SET}) allow the user to program supply current, slew-rate, and input noise without the usual sacrifice of gain bandwidth product. For example, the user can trade-off slew-rate for supply current or optimize the noise figure for a given source impedance. Except for the two programming pins at the end of the package, the XR-094 and XR-095 pin-out is the same as the popular 324, 3403, 124, 148 and 4741 operational amplifiers.

In the case of the XR-094, three of the op amps on the chip share a common programming pin; and the fourth op amp is programmed separately. In the case of the XR-095, each pair of op amps share a common programming pin.

FEATURES

- Same Pin Configuration as LM-346
- High-Impedance FET Input Stage
- Internal Frequency Compensation
- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Output Short-Circuit Protection
- High Slew-Rate . . . 13 V/ μ s, Typical
- Programmable Electrical Characteristics

APPLICATIONS

Total Supply Current = 5.6 mA ($I_{SET}/320 \mu A$)
 Slew Rate = 13 V/ μ s ($I_{SET}/320 \mu A$)
 I_{SET} = Current into set terminal

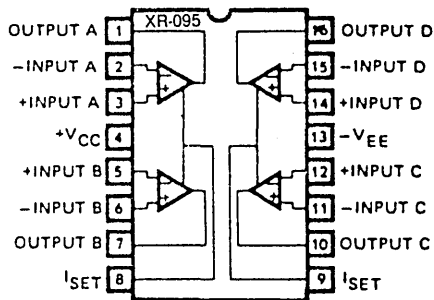
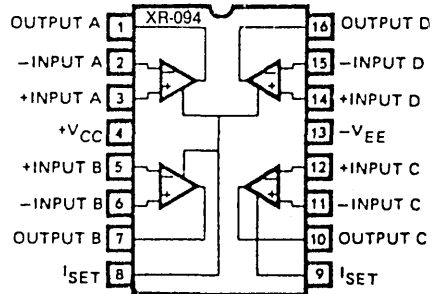
$$I_{SET} = \frac{V_{CC} - (V_{EE} - 0.6V)}{R_{SET}}$$

Note: I_{SET} must be $\leq 400 \mu A$

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	$\pm 18V$
Differential Input Voltage	$\pm 30V$
Input Voltage Range (Note 1)	$\pm 15V$
Output Short-Circuit Duration (Note 2)	Indefinite
Package Power Dissipation:	
Plastic Package	625 mW

FUNCTIONAL BLOCK DIAGRAMS



ABSOLUTE MAXIMUM RATINGS (Continued)

Derate Above $T_A = +25^\circ C$	5.0 mV/ $^\circ C$
Ceramic Package	750 mW
Derate Above $T_A = +25^\circ C$	6.0 mW/ $^\circ C$
Storage Temperature Range	$-65^\circ C$ to $+150^\circ C$

Note 1: For Supply Voltage less than $\pm 15V$, the absolute maximum input voltage is equal to the supply voltage.

Note 2: The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

ORDERING INFORMATION

Part Number	Package	Operating Temperature
XR-094/XR-095N	Ceramic	$-25^\circ C$ to $+85^\circ C$
XR-094/XR-095P	Plastic	$-25^\circ C$ to $+85^\circ C$
XR-094/XR-095CN	Ceramic	$0^\circ C$ to $+70^\circ C$
XR-094/XR-095CP	Plastic	$0^\circ C$ to $+70^\circ C$

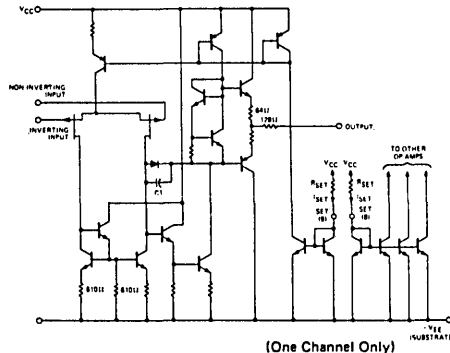
XR-094/095

ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_{CC} = \pm 15\text{V}$, unless otherwise specified.

$I_{SET} = 320 \mu\text{A}$.

PARAMETERS	XR-094/095			XR-094/095C			UNITS	SYMBOL	CONDITIONS
	MIN	TYP	MAX	MIN	TYP	MAX			
Input Offset Voltage		3	6 9		5	15 20	mV mV	V_{OS} V_{OS}	$R_S = 50\Omega$, $T_A = 25^\circ\text{C}$ $R_S = 50\Omega$, $T_A = \text{Full Range}$
Offset Voltage Temp. Coef.		10			10		$\mu\text{V}/^\circ\text{C}$	$\Delta V_{OS}/\Delta T$	$R_S = 50\Omega$, $T_A = \text{Full Range}$
Input Bias Current		80	600 20		80	800 20	pA nA	I_B	$T_A = 25^\circ\text{C}$ $T_A = \text{Full Range}$
Input Offset Current		40	300 10		40	500 5	pA nA	I_{OS}	$T_A = 25^\circ\text{C}$ $T_A = \text{Full Range}$
Supply Current (per amplifier)		1.4	2.8		1.4	2.8	mA	I_{CC}	No Load, No Input Signal
Input Common Mode Range	± 12			± 10			V	V_{ICM}	
Voltage Gain	50 25	200		25 15	200		V/mV	A_{VOL}	$R_L \geq 2\text{K}\Omega$, $V_O = \pm 10\text{V}$ $T_A = 25^\circ\text{C}$ $T_A = \text{Full Range}$
Max. Output Swing (peak-to-peak)	24 24	27		24 24	27		V	V_{OPP}	$R_L \geq 10\text{K}\Omega$ $T_A = 25^\circ\text{C}$ $T_A = \text{Full Range}$
Input Resistance		10^{12}			10^{12}		Ω	R_{in}	$T_A = 25^\circ\text{C}$
Unity-Gain Bandwidth		3			3		MHz	BW	$T_A = 25^\circ\text{C}$
Common-Mode Rejection	80	86		70	76		dB	CMRR	$R_S \leq 10\text{K}\Omega$
Supply-Voltage Rejection	80	86		70	76		dB	PSRR	
Channel Separation		120			120		dB		$A_V = 100$, Freq. = 1 kHz
Slew Rate		13			13		V/ μS	dV_{out}/dt	$A_V = 1$, $R_L = 2\text{K}\Omega$ $C_L = 100\text{pF}$, $V_1 = 10\text{V}$
Rise Time Overshoot		0.1 10			0.1 10		μsec %	t_r t_o	$A_V = 1$, $R_L = 2\text{K}\Omega$ $C_L = 100\text{pF}$, $V_1 = 20\text{mV}$
Equivalent Input Noise Voltage		18			18		nV/ $\sqrt{\text{Hz}}$	e_n	$R_S = 100\Omega$ $f = 1\text{kHz}$



EQUIVALENT SCHEMATIC DIAGRAM